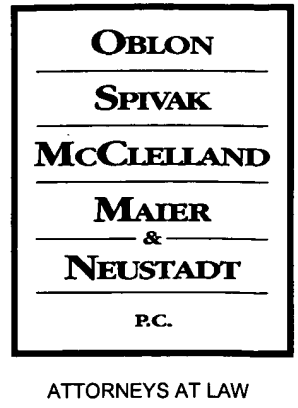




Docket No.: 250630US2S



COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

RE: Application Serial No.: 10/802,799
Applicants: Takeshi WATANABE, et al.
Filing Date: March 18, 2004
For: SEMICONDUCTOR MEMORY INCLUDING
STATIC RANDOM ACCESS MEMORY FORMED
OF FINFET
Group Art Unit: 2824
Examiner: NGUYEN, DANG T.

SIR:

Attached hereto for filing are the following papers:

Submission of Supplemental Application Data Sheet, Supplemental Application Data Sheet

Our check in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.


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